

1N4150

FAST SWITCHING SURFACE MOUNT DIODES

VOLTAGE 50 Volts **POWER** 500 mWatts

DO-35

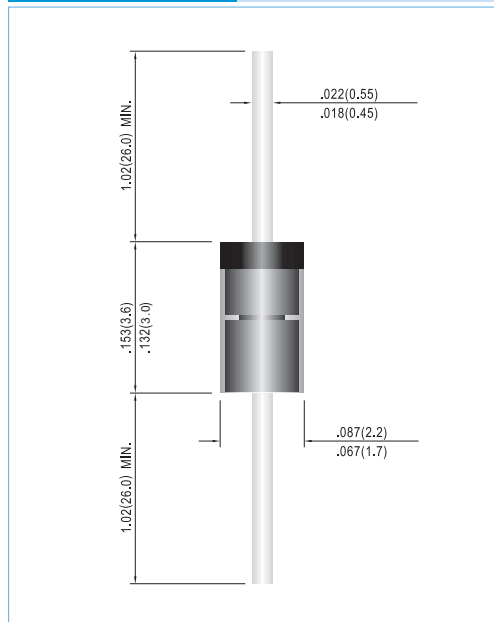
Unit: inch (mm)

FEATURES

- Fast switching Speed.
- Surface Mount Package Ideally Suited For Automatic Insertion.
- Silicon Epitaxial Planar Construction.
- Lead free in comply with EU RoHS 2002/95/EC directives

MECHANICAL DATA

- Case: Mini Melf, Glass
- Terminals: Solderable per MIL-STD-750, Method 2026
- Polarity: See Diagram Below
- Approx. Weight: 0.13 grams
- Mounting Position: Any
- Ordering information: Suffix : " -35 " to order DO-35 Package
- Packing information
 - B - 2K per Bulk box
 - T/R - 10K per 15" plastic Reel
 - T/B - 5K per horiz. tape & Ammo box



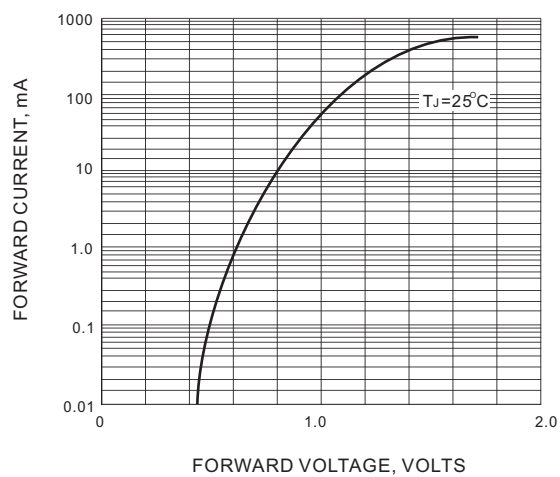
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_J=25°C unless otherwise noted)

PARAMETER	SYMBOL	1N4150	UNITS
Reverse Voltage	V _R	50	V
Peak Reverse Voltage	V _{RM}	50	V
RMS Voltage	V _{RMS}	35	V
Maximum Average Forward Current at T _A =25°C And f ≥ 50Hz	I _{F(AV)}	200	mA
Surge Forward Current at t < 1s and T _J =25 °C	I _{FSM}	500	mA
Power Dissipation at Tamb= 25 °C	P _{TOT}	500	mW
Maximum Forward Voltage at I _F =200mA	V _F	1.0	V
Maximum Leakage Current at V _R = 50V	I _R	0.1	μA
Maximum Capacitance (Note 1)	C _J	4	pF
Maximum Reverse Recovery Time (Note 2)	t _{rr}	4	ns
Typical Thermal Resistance	R _{θJA}	350	°C / W
Junction Temperature and Storage Temperature Range	T _J , T _S	-65 to +175	°C

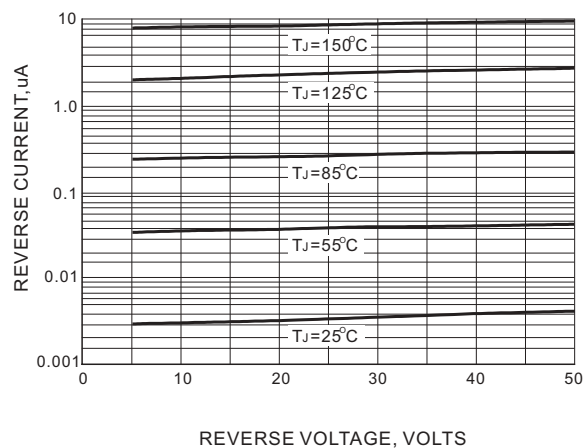
NOTE:

1. C_J at V_R=0, f=1MHZ
2. From I_F=10mA to I_R=1mA, V_R=6Volts, R_L=100Ω

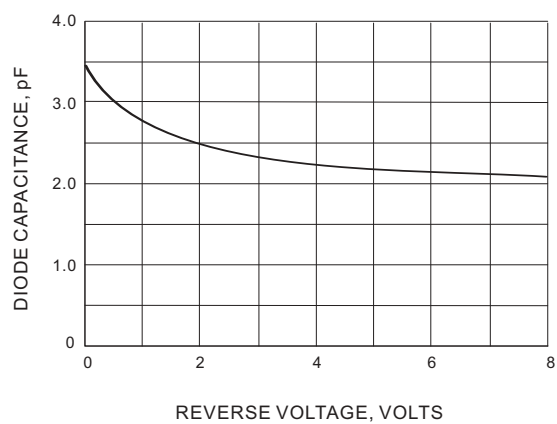
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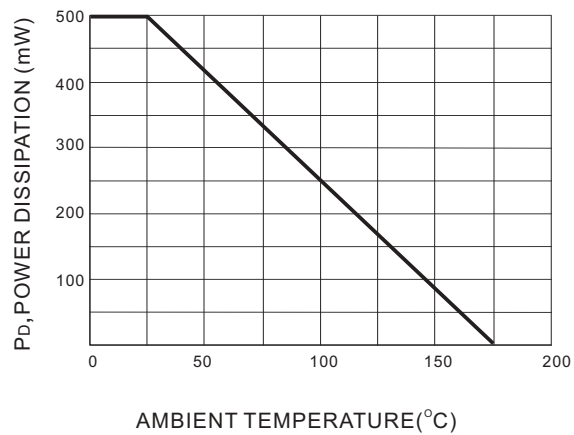
FORWARD VOLTAGE



LEAKAGE CURRENT



TYPICAL CAPATICANCE



POWER DERATING